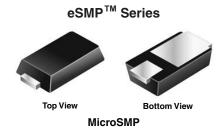


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Surface Mount Schottky Barrier Rectifiers

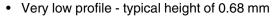


PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 A			
V _{RRM}	20 V, 30 V			
I _{FSM}	30 A			
V _F at I _F = 2.0 A	0.47 V			
T _J max.	150 °C			

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

FEATURES





· Ideal for automated placement

Low forward voltage drop, low power losses



COMPLIANT

· High efficiency

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"Green" molding compound (GMC)

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

Case: MicroSMP

Molding compound meets UL 94V-0 flammability rating.

"G" vs. "E" suffix defines molding as none green, "E", or green molding compound (GMC) "G".

"G" is defined as halogen-free (HF) and antimony-free molding compound that is < 50 ppm for F, Cl, Br, I and At, and < 5 ppm for Sb.

Note:

 There is no industry standard for definition of HF, or GMC for components.

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test. "E3" terminal finish per J-STD-609

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS2P2	MSS2P3	UNIT	
Device marking code		22	23		
Maximum repetitive peak reverse voltage	V_{RRM}	20 30		V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.0		А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30		А	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150		°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 1.0 A I _F = 2.0 A	T _A = 25 °C	V _F	0.44 0.52	- 0.60	V
	I _F = 1.0 A I _F = 2.0 A	T _A = 125 °C		0.36 0.47	- 0.55	
Maximum reverse current (1)	rated V _R	T _A = 25 °C T _A = 125 °C	I _R	15 6.0	250 20	μA mA
Typical junction capacitance	4.0 V, 1 MH	4.0 V, 1 MHz		65	-	pF

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MSS2P2	MSS2P3	UNIT
Typical thermal resistance ⁽¹⁾	$egin{array}{l} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	105 15 20		°C/W

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
MSS2P3-E3/89A	0.006	89A	4500	7" diameter plastic tape and reel		
MSS2P3-G3/89A	0.006	89A	4500	7" diameter plastic tape and reel		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

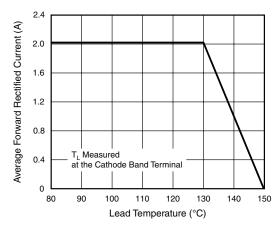


Figure 1. Forward Current Derating Curve

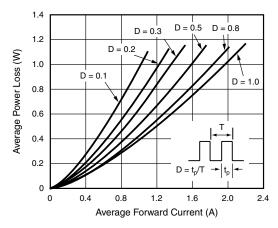


Figure 2. Forward Power Loss Characteristics



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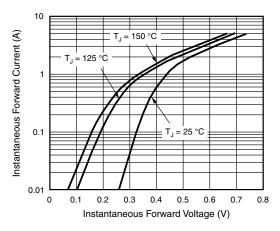


Figure 3. Typical Instantaneous Forward Characteristics

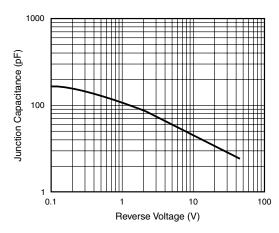


Figure 5. Typical Junction Capacitance

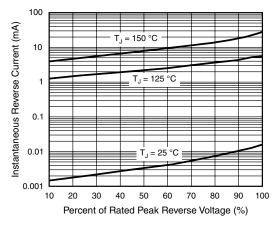


Figure 4. Typical Reverse Characteristics

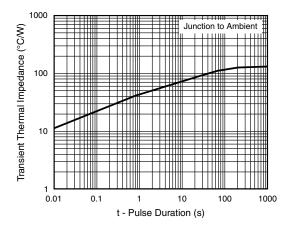
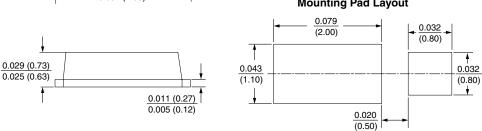


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

MicroSMP 0.059 (1.50) 0.030 (0.75) Cathode Band 0.043 (1.10) 0.022 (0.55) 0.030 (0.75) 0.055 (1.40) 0.039 (0.98) 0.047 (1.20) 0.031 (0.78) 0.022 (0.55) 0.091 (2.30) 0.083 (2.10) 0.106 (2.70) 0.091 (2.30) **Mounting Pad Layout**



Document Number: 89054 Revision: 14-Apr-08 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com

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